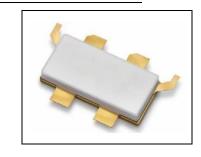
2.0-6.0GHz, 40W, GaN Fully matched PA Module

Description

The GMAH2060-40B4V is a 40-watt, single stage integrated Power Amplifier Module, designed For application with frequencies from 2.0 to 6.0GHz. Within 2-4GHz, it can deliver 50W CW.

The module is 50 Ω input/output matched and requires minimal external components.

There is no guarantee when device used outside the stated bands



			, ,		1			
Freq(MHz)	Pin(dBm)	Pout(dBm)	Pout(W)	IDS(A)		Eff(%)	2 nd	3 rd
1 (Cq((VII 12)	i iii(dbiii)	1 oat(abiii)	1 Out(VV)	IDO(A)	Gain(dB)	L11(70)	Harmonic	Harmonic
2000	38.40	48.70	74.1	4.82	10.30	54.9	-19.4	-13.0
2500	38.60	48.02	63.4	4.63	9.42	48.9	-13.4	-17.8
2800	39.15	47.37	54.6	5.10	8.22	38.2	-13.7	-34.7
3000	39.45	47.86	61.1	5.54	8.41	39.4	-13.6	-40.6
3500	36.70	48.70	74.1	4.74	12.00	55.9	-16.2	-40.0
4000	37.02	47.87	61.2	4.08	10.85	53.6	-36.1	-57.0
4500	38.55	46.65	46.2	4.69	8.10	35.2	-	-
5000	39.25	47.00	50.1	5.10	7.75	35.1	-	-

4.35

3.88

8.87

8.27

42.3

43.3

51.5

47.0

 $V_{DS} = 28V$, $V_{GS} = -2.45V$, $I_{dq} = 200mA$

6000 38.45

Product Features

5500

• Operating Frequency Range: 2.0-6.0GHz

38.25

- Operating Drain Voltage(Recommended): +28V (Up to 32V)
- 50 Ω Input/Output (External DC block capacitor needed)
- Psat≥40W (CW)
- Small signal gain:>12dB, Power gain:>8dB
- Minimum Psat efficiency:>35%
- 20*10 mm metal RF package
- Compliant to Restriction of Hazardous Substances (RoHS) Directive 2002/95/EC

47.12

46.72

Applications

- Power Amplifiers within L/S/C band
- Test Instrumentation
- EMC Amplifier Drivers
- 2-way Radios

Table 1. Maximum Ratings

Rating	Symbol	Value	Unit
DrainSource Voltage	$V_{ t DSS}$	150	Vdc
GateSource Voltage	V_{GS}	-10 to +2	Vdc
Operating Voltage	V_{DD}	+32	Vdc
Storage Temperature Range	Tstg	-65 to +150	°C
Case Operating Temperature	Tc	+150	°C



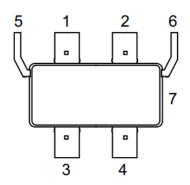
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perating Junction Temperature	TJ	+225	°C
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Table 2. Thermal Characteristics

Characteristic	Symbol	Value	Unit
Thermal Resistance, Junction to Case	Do 10	2.0	°C/W
T _C = 25°C, Pout=40W at 5GHz, FEA	Rejc	2.0	-0/00

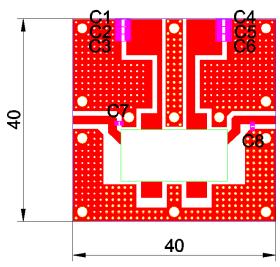
Pin Definition



Pin No.	Symbol	Description
5	Pin	RF Input
6	Pout	RF Output
1	Vgs	Gate Bias
2	Vds	Drain Bias
3,4	NC	No connection
7	Source	Source, grounding



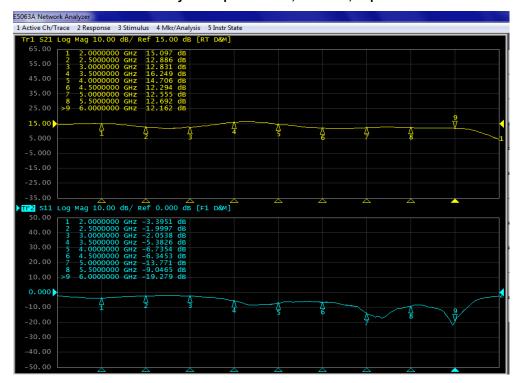
Typical application circuit



Component	Description	Suggested Manufacturer / Series Number
C1 C4	10 uF	TDK
C2 C5	120 pF	MQ301111
C3 C6	8.2 pF	MQ301111
C7	0.3 pF	ATC 600F
C8	0.2 pF	ATC 600F
PCB	30Mil Rogers 4350	Rogers

Typical performance

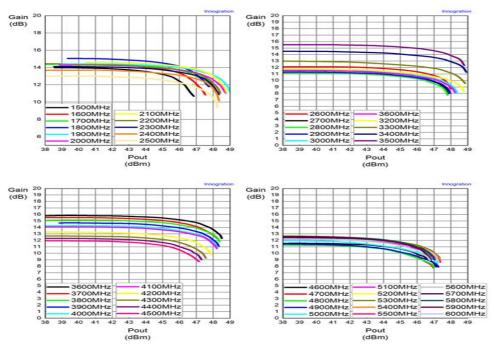
Network analyzer output S21/S11, Vds=28V, Idq=200mA



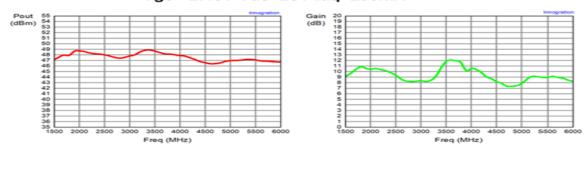


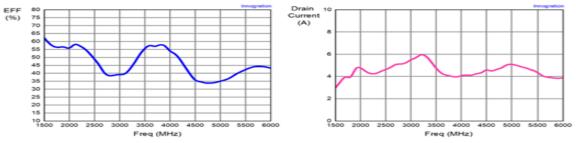
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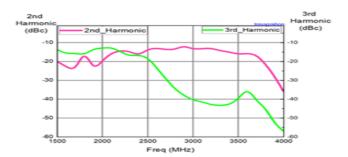
Pulse 100us 10% Vgs=-2.45V Vds=28V Idq=200mA



CW Test Vgs=-2.45V Vds=28V Idq=200mA



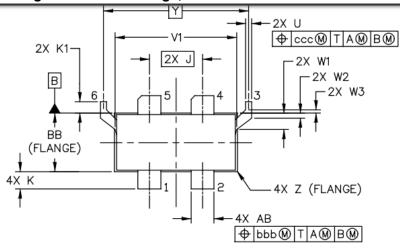


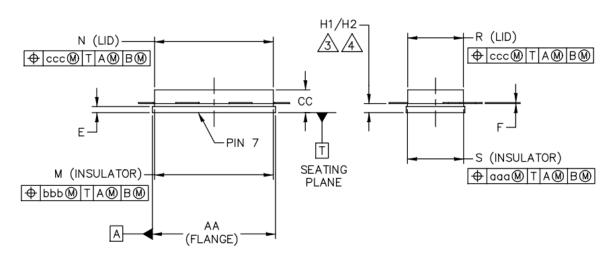




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Earless Flanged Ceramic Package; 6 leads- BY4V





	INCH		MILLIMETER			INCH		MILLIMETER	
DIM	MIN	MAX	MIN	MAX	DIM	MIN	MAX	MIN	MAX
AA	.805	.815	20.45	20.70	R	.365	.375	9.27	9.53
BB	.380	.390	9.65	9.91	S	.365	.375	9.27	9.53
CC	.125	.170	3.18	4.32	U	.035	.045	0.89	1.14
Ε	.035	.045	0.89	1.14	V1	.795	.805	20.19	20.45
F	.004	.007	0.10	0.18	W1	.0975	.1175	2.48	2.98
H1	.057	.067	1.45	1.70	W2	.0225	.0425	0.57	1.08
H2	.054	.070	1.37	1.78	W3	.0125	.0325	0.32	0.83
J	J .350 BSC		8.89	BSC	Y	.956	BSC	24.28	B BSC
K	.0995	.1295	2.53	3.29	Z	R.000	R.040	R0.00	R1.02
K1	.070	.090	1.78	2.29	AB	.145	.155	3.68	3.94
М	.774	.786	19.66	19.96	aaa	.0	005	0.1	3
Ν	.772	.788	19.61	20.02	bbb	.c	010	0.2	25
					ccc	.0)15	0.3	88



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Revision history

Table 6. Document revision history

Date	Revision	Datasheet Status			
2025/8/14	Rev 1.0	Advanced Datasheet			
2025/9/11	Rev 1.0	Preliminary datasheet, finalized from 1.5-6GHz to 2-6GHz, Rth modification			

Application data based on JF-25-17

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